

September 1983 Revised May 2005

MM74HC14

Hex Inverting Schmitt Trigger

General Description

The MM74HC14 utilizes advanced silicon-gate CMOS technology to achieve the low power dissipation and high noise immunity of standard CMOS, as well as the capability to drive 10 LS-TTL loads.

The 74HC logic family is functionally and pinout compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to $V_{\mbox{\footnotesize CC}}$ and ground.

Features

- Typical propagation delay: 13 ns
- Wide power supply range: 2-6V
- Low quiescent current: 20 µA maximum (74HC Series)
- Low input current: 1 µA maximum
- Fanout of 10 LS-TTL loads
- Typical hysteresis voltage: 0.9V at V_{CC} = 4.5V

Ordering Code:

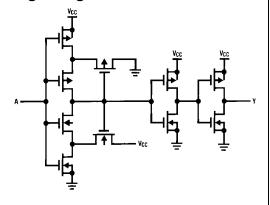
Order Number	Package Number	Package Description
MM74HC14M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC14MX_NL	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC14SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC14MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC14MTCX_NL	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC14N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74HC14N_NL	N14A	Pb-Free 14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. Pb-Free package per JEDEC J-STD-020B.

Connection Diagram

Pin Assignments for DIP, SOIC, SOP and TSSOP **Top View**

Logic Diagram



Absolute Maximum Ratings(Note 1)

(Note 2)

Recommended Operating Conditions

Supply Voltage (V_{CC}) DC Input or Output Voltage (V_{IN}, V_{OUT}) Operating Temperature Range (T_A) -55 +125

DC V_{CC} or GND Current, per pin ±50 mA

-0.5 to +7.0V

±20 mA

±25 mA

260°C

-1.5 to $V_{CC} + 1.5V$

-0.5 to V_{CC} +0.5V

Storage Temperature Range (T_{STG}) -65°C to +150°C

Power Dissipation (P_D)

Supply Voltage (V_{CC})

DC Input Voltage (V_{IN})

DC Output Voltage (V_{OUT})

Clamp Diode Current (I_{IK}, I_{OK})

DC Output Current, per pin (I_{OUT})

(Note 3) 600 mW S.O. Package only 500 mW

Lead Temperature (T_L)

(Soldering 10 seconds)

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Max Units

V

°C

 V_{CC}

Note 2: Unless otherwise specified all voltages are referenced to ground. Note 3: Power Dissipation temperature derating — plastic "N" package: -

12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V _{CC}	T _A = 25°C		T _A = -40 to 85°C	T _A = -55 to 125°C	Units
	raiailletei		*cc	Тур		Guaranteed L	imits	Units
V _{T+}	Positive Going	Minimum	2.0V	1.2	1.0	1.0	1.0	V
	Threshold Voltage		4.5V	2.7	2.0	2.0	2.0	V
			6.0V	3.2	3.0	3.0	3.0	V
		Maximum	2.0V	1.2	1.5	1.5	1.5	V
			4.5V	2.7	3.15	3.15	3.15	V
			6.0V	3.2	4.2	4.2	4.2	V
V _{T-}	Negative Going	Minimum	2.0V	0.7	0.3	0.3	0.3	V
	Threshold Voltage		4.5V	1.8	0.9	0.9	0.9	V
			6.0V	2.2	1.2	1.2	1.2	V
		Maximum	2.0V	0.7	1.0	1.0	1.0	V
			4.5V	1.8	2.2	2.2	2.2	V
			6.0V	2.2	3.0	3.0	3.0	V
V _H	Hysteresis Voltage	Minimum	2.0V	0.5	0.2	0.2	0.2	V
			4.5V	0.9	0.4	0.4	0.4	V
			6.0V	1.0	0.5	0.5	0.5	V
		Maximum	2.0V	0.5	1.0	1.0	1.0	V
			4.5V	0.9	1.4	1.4	1.4	V
			6.0V	1.0	1.5	1.5	1.5	V
V _{OH}	Minimum HIGH Level	$V_{IN} = V_{IL}$	2.0V	2.0	1.9	1.9	1.9	V
	Output Voltage	$ I_{OUT} = 20 \mu A$	4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		$V_{IN} = V_{IL}$						
		$ I_{OUT} = 4.0 \text{ mA}$	4.5V	4.2	3.98	3.84	3.7	V
		$ I_{OUT} = 5.2 \text{ mA}$	6.0V	5.7	5.48	5.34	5.2	V
V _{OL}	Maximum LOW Level	$V_{IN} = V_{IH}$	2.0V	0	0.1	0.1	0.1	V
	Output Voltage	$ I_{OUT} = 20 \mu A$	4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		$V_{IN} = V_{IH}$						
		$ I_{OUT} = 4.0 \text{ mA}$	4.5V	0.2	0.26	0.33	0.4	V
		I _{OUT} = 5.2 mA	6.0V	0.2	0.26	0.33	0.4	V
I _{IN}	Maximum Input Current	V _{IN} = V _{CC} or GND	6.0V		±0.1	±1.0	±1.0	μА
I _{CC}	Maximum Quiescent	V _{IN} = V _{CC} or GND	6.0V		2.0	20	40	μА
	Supply Current	$I_{OUT} = 0 \mu A$						

Note 4: For a power supply of 5V ±10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at $V_{CC} = 5.5V$ and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage curvature of the V_{IH} value at 5.5V is 3.85V.) rent (I_{IN} , I_{CC} , and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

 $V_{CC} = 5V$, $T_A = 25^{\circ}C$, $C_L = 15$ pF, $t_r = t_f = 6$ ns

S	ymbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
t _{PHL}	, t _{PLH}	Maximum Propagation Delay		12	22	ns

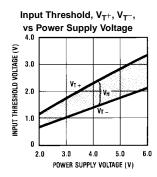
AC Electrical Characteristics

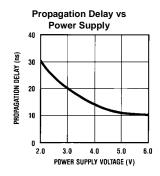
 V_{CC} = 2.0V to 6.0V, C_L = 50 pF, t_r = t_f = 6 ns (unless otherwise specified)

Symbol	Parameter	Conditions	V _{CC}	T _A = 25°C		T _A = -40 to 85°C	T _A = -55 to 125°C	Units	
Cyllibol	i arameter			Typ Guaranteed Limits					
t_{PHL}, t_{PLH}	Maximum Propagation		2.0V	60	125	156	188	ns	
	Delay		4.5V	13	25	31	38	ns	
			6.0V	11	21	26	32	ns	
t _{TLH} , t _{THL}	Maximum Output Rise		2.0V	30	75	95	110	ns	
	and Fall Time		4.5V	8	15	19	22	ns	
			6.0V	7	13	16	19	ns	
C _{PD}	Power Dissipation	(per gate)		27				pF	
	Capacitance (Note 5)								
C _{IN}	Maximum Input Capacitance			5	10	10	10	pF	

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} \ V_{CC} 2 \ f + I_{CC} \ V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} \ V_{CC} \ f + I_{CC}$.

Typical Performance Characteristics





Typical Applications

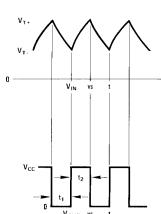
Low Power Oscillator



$$t_1 \approx RC \ ln \, \frac{V_{T\,+}}{V_{T\,-}}$$

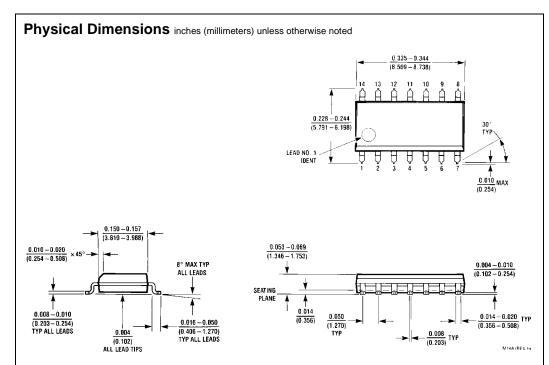
$$t_2 \approx RC \ln \frac{V_{CC} - V_{T-}}{V_{CC} - V_{T+}}$$

V_{CC} -----

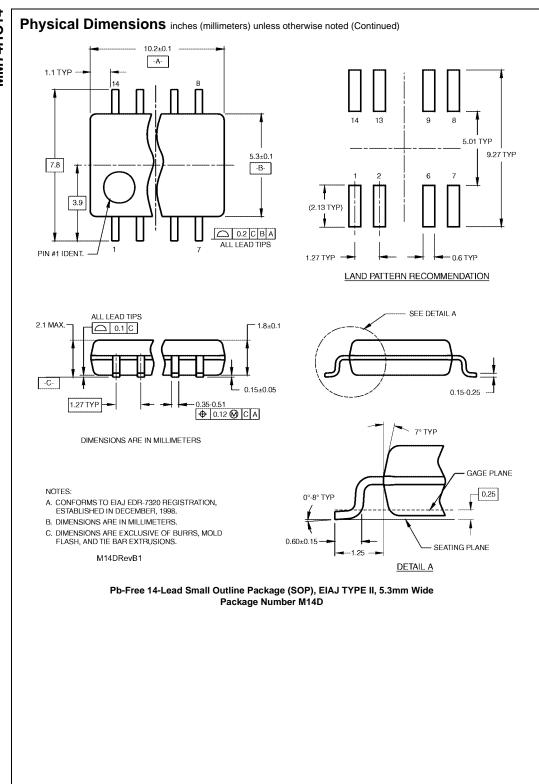


$$f \approx \frac{1}{RC \ln \frac{V_{T+}(V_{CC} - V_{T-})}{V_{T-}(V_{CC} - V_{T+})}}$$

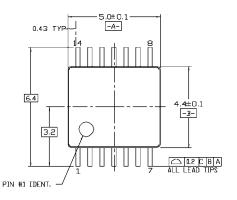
Note: The equations assume t_1^+ $t_2^- >> t_{pd0}^-$ + t_{pd1}^-

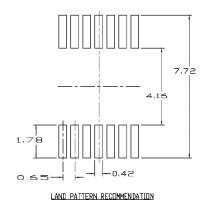


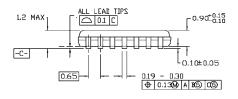
14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Package Number M14A

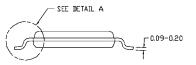


Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





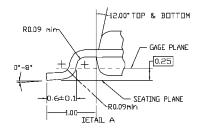




NOTES:

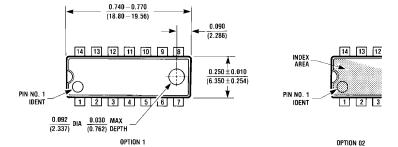
- A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION AB, REF NOTE 6, DATED 7/93
- B. DIMENSIONS ARE IN MILLIMETERS
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS
 D. DIMENSIONING AND TOLERANCES PER ANSI Y14-5M, BOX

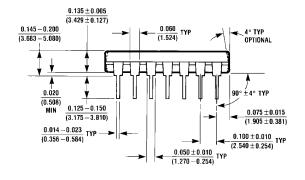
MTC14revD

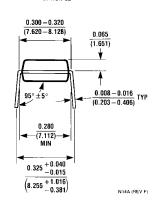


14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)







14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N14A

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